TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC7MH367FK,TC7MH368FK**

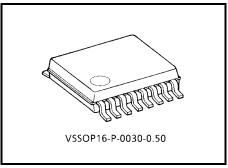
HEX Bus Buffer

TC7MH367FK Non-Inverted, 3-State Outputs TC7MH368FK Inverted, 3-State Outputs

The TC7MH367FK and TC7MH368FK are advanced high speed CMOS HEX bus buffers fabricated with silicon gate  $C^2MOS$  technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input ( $\overline{G}1$ ), and the other two buffers are controlled by another enable input ( $\overline{G}2$ ). The outputs of each buffer group are enabled when  $\overline{G}1$  and/or  $\overline{G}2$  inputs are held low; if held high, these outputs are in a high impedance state.



Weight: 0.02 g (typ.)

The TC7MH367FK is a non-inverting output type, while the TC7MH368FK is an inverting output type.

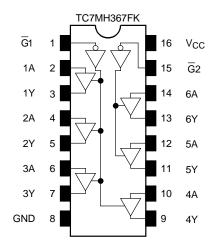
An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

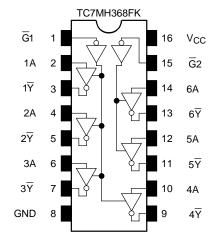
#### Features

- High speed:  $t_{pd} = 3.8 \text{ ns} (typ.) (V_{CC} = 5 \text{ V})$
- Low power dissipation:  $I_{CC} = 4 \ \mu A \ (max) \ (Ta = 25^{\circ}C)$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: VCC (opr) =  $2 \sim 5.5$  V
- Low noise:  $V_{OLP} = 0.8 V (max)$
- Pin and function compatible with 74ALS367/368

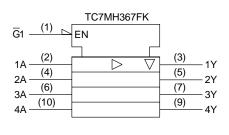
# <u>TOSHIBA</u>

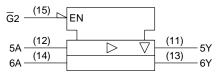
#### Pin Assignment (top view)





#### **IEC Logic Symbol**



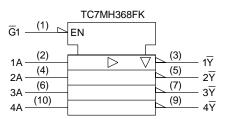


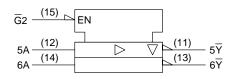
#### **Truth Table**

| Inp | uts | Outputs |                                |  |  |  |
|-----|-----|---------|--------------------------------|--|--|--|
| G   | А   | Y (367) | <del>-</del><br><u>Y</u> (368) |  |  |  |
| L   | L   | L       | Н                              |  |  |  |
| L   | Н   | Н       | L                              |  |  |  |
| Н   | Х   | Z       | Z                              |  |  |  |

X: Don't care

Z: High impedance





## **Maximum Ratings**

| Characteristics                    | Symbol           | Rating                   | Unit |
|------------------------------------|------------------|--------------------------|------|
| Supply voltage range               | V <sub>CC</sub>  | -0.5~7.0                 | V    |
| DC input voltage                   | V <sub>IN</sub>  | -0.5~7.0                 | V    |
| DC output voltage                  | V <sub>OUT</sub> | $-0.5 \sim V_{CC} + 0.5$ | V    |
| Input diode current                | I <sub>IK</sub>  | -20                      | mA   |
| Output diode current               | I <sub>OK</sub>  | ±20                      | mA   |
| DC output current                  | IOUT             | ±25                      | mA   |
| DC V <sub>CC</sub> /ground current | ICC              | ±50                      | mA   |
| Power dissipation                  | PD               | 180                      | mW   |
| Storage temperature                | T <sub>stg</sub> | -65~150                  | °C   |

# **Recommended Operating Conditions**

| Characteristics          | Symbol           | Rating                                 | Unit   |
|--------------------------|------------------|--|--------|
| Supply voltage           | V <sub>CC</sub>  | 2.0~5.5                                | V      |
| Input voltage            | V <sub>IN</sub>  | 0~5.5                                  | V      |
| Output voltage           | V <sub>OUT</sub> | 0~V <sub>CC</sub>                      | V      |
| Operating temperature    | T <sub>opr</sub> | -40~85                                 | °C     |
| Input rise and fall time | dt/dv            | 0~100 (V_{CC} = 3.3 $\pm$ 0.3 V)       | ns/V   |
| input lise and fair time | ui/uv            | 0~20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V) | 115/ V |

#### **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics   |                           | Symbol          | Symbol Test Condi  |                          | Condition   |                     | Ta = 25°C |   |                     | Ta = -40~85°C |      |
|-------------------|---------------------------|-----------------|--|--------------------------|-------------|---------------------|-----------|---|---------------------|---------------|------|
| Characte          | ISUCS                     | Symbol          | Symbol Test Condition  |                          | $V_{CC}(V)$ | Min                 | Тур.      | Max   | Min                 | Max           | Unit |
| High level        |                           |                 | —  |                          | 2.0         | 1.50                | _         | _   | 1.50                | _             | V    |
|                   |                           | VIH             |  |                          | 3.0~5.5     | $V_{CC} \times 0.7$ | _         |   | $V_{CC} \times 0.7$ |               |      |
| input voltage     |                           |                 |  |                          | 2.0         |                     |           | 0.50  | _                   | 0.50          | v    |
|                   | Low level V <sub>IL</sub> |                 | 3.0~5.5  |                          | _           | $V_{CC} \times 0.3$ | _         | $\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$ |                     |               |      |
|                   |                           |                 |  | I <sub>OH</sub> = -50 μA | 2.0         | 1.9                 | 2.0       |   | 1.9                 | _             |      |
|                   |                           |                 | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub>                    |                          | 3.0         | 2.9                 | 3.0       |   | 2.9                 | _             |      |
| Output voltage    | High level                | V <sub>OH</sub> |  |                          | 4.5         | 4.4                 | 4.5       |   | 4.4                 | —             |      |
|                   |                           |                 |  | $I_{OH} = -4 \text{ mA}$ | 3.0         | 2.58                | —         |   | 2.48                | —             |      |
|                   |                           |                 |  | $I_{OH} = -8 \text{ mA}$ | 4.5         | 3.94                | —         |   | 3.80                | —             |      |
| oulput voltago    |                           |                 | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub>                    | I <sub>OL</sub> = 50 μA  | 2.0         | _                   | 0         | 0.1   |                     | 0.1           |      |
|                   |                           |                 |  |                          | 3.0         | _                   | 0         | 0.1   | —                   | 0.1           |      |
|                   | Low level                 | VoL             |  |                          | 4.5         | _                   | 0         | 0.1   | —                   | 0.1           |      |
|                   |                           |                 |  | $I_{OL} = 4 \text{ mA}$  | 3.0         | _                   |           | 0.36  |                     | 0.44          |      |
|                   |                           |                 | $I_{OL} = 8 \text{ mA}$  | 4.5                      | _           | _                   | 0.36      |   | 0.44                |               |      |
| 3-state output of | f-state current           | I <sub>OZ</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = V_{CC} \text{ or } GND$ |                          | 5.5         | _                   | _         | ±0.25   | _                   | ±2.50         | μΑ   |
| Input leakage cu  | rrent                     | I <sub>IN</sub> | $V_{IN} = 5.5 \text{ V or GND}$  |                          | 0~5.5       |                     |           | ±0.1  |                     | ±1.0          | μΑ   |
| Quiescent supply  | y current                 | Icc             | $V_{IN} = V_{CC} \text{ or } GND$  |                          | 5.5         |                     | _         | 4.0   | _                   | 40.0          | μΑ   |

#### AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics                  | Symbol Test Condition                |                     |                               |           | Ta = 25°C |     |      | Ta = -4 | Unit |     |
|----------------------------------|--------------------------------------|---------------------|-------------------------------|-----------|-----------|-----|------|---------|------|-----|
|                                  | Test Condition                       | V <sub>CC</sub> (V) | C <sub>L</sub> (pF)           | Min       | Тур.      | Max | Min  | Max     | Unit |     |
|                                  |                                      |                     | 3.3 ± 0.3                     | 15        | _         | 5.9 | 8.3  | 1.0     | 10.0 |     |
| Propagation delay time           | t <sub>pLH</sub>                     |                     | 5.5 ± 0.5                     | 50        | _         | 8.4 | 11.8 | 1.0     | 13.5 | ns  |
| (TC7MH367)                       | t <sub>pHL</sub>                     |                     | 5.0 ± 0.5                     | 15        |           | 4.1 | 5.9  | 1.0     | 7.0  | 113 |
|                                  |                                      |                     | 5.0 ± 0.5                     | 50        |           | 5.6 | 7.9  | 1.0     | 9.0  |     |
|                                  |                                      |                     | 3.3 ± 0.3                     | 15        |           | 5.3 | 7.5  | 1.0     | 9.0  |     |
| Propagation delay time           | t <sub>pLH</sub>                     |                     | 5.5 ± 0.5                     | 50        |           | 7.8 | 11.0 | 1.0     | 12.5 | ns  |
| (TC7MH368)                       | tpHL                                 |                     |                               | 5.0 ± 0.5 | 15        |     | 3.8  | 5.5     | 1.0  | 6.5 |
|                                  |                                      |                     | 5.0 ± 0.5                     | 50        |           | 5.3 | 7.5  | 1.0     | 8.5  |     |
|                                  | t <sub>pZL</sub><br>t <sub>pZH</sub> | $R_L = 1 \ k\Omega$ | $3.3 \pm 0.3$                 | 15        |           | 6.8 | 10.5 | 1.0     | 12.5 | ns  |
| 3-state output enable time       |                                      |                     |                               | 50        |           | 9.3 | 14.0 | 1.0     | 16.0 |     |
| 3-state output enable time       |                                      |                     |                               | 15        |           | 4.8 | 7.2  | 1.0     | 8.5  |     |
|                                  |                                      |                     |                               | 50        |           | 6.3 | 9.2  | 1.0     | 10.5 |     |
| 3-state output disable time      | t <sub>pLZ</sub>                     | $R_{I} = 1 k\Omega$ | $\textbf{3.3}\pm\textbf{0.3}$ | 50        |           | 9.9 | 13.6 | 1.0     | 15.5 | ns  |
| 5-state output disable time      | t <sub>pHZ</sub>                     | NL - 1 K22          | $5.0\pm0.5$                   | 50        |           | 6.3 | 9.2  | 1.0     | 10.5 | 113 |
| Output to output skew            | t <sub>osLH</sub>                    | (Note1)             | $\textbf{3.3}\pm\textbf{0.3}$ | 50        |           |     | 1.5  |         | 1.5  | ns  |
|                                  | t <sub>osHL</sub>                    | (Note I)            | $5.0\pm0.5$                   | 50        |           |     | 1.0  | _       | 1.0  | 113 |
| Input capacitance                | C <sub>IN</sub>                      | -                   | _                             |           | _         | 4   | 10   | _       | 10   | pF  |
| Output capacitance               | C <sub>OUT</sub>                     | _                   | _                             |           | _         | 6   | _    |         |      | pF  |
| Power dissipation<br>capacitance | C <sub>PD</sub>                      |                     |                               | (Note2)   | _         | 19  | _    | _       | _    | pF  |

Note1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ 

Note2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

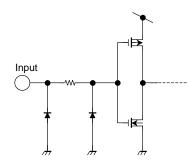
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per bit)}$ 

## Noise Characteristics (Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

| Characteristics                                   | Symbol           | Test Condition         | _           | Ta = 25°C |       | Unit |
|---|------------------|------------------------|-------------|-----------|-------|------|
| Characteristics                                   | Symbol           | Test Condition         | $V_{CC}(V)$ | Тур.      | Limit | Unit |
| Quiet output maximum dynamic $V_{OL}$             | V <sub>OLP</sub> | $C_L = 50 \text{ pF}$  | 5.0         | 0.4       | 0.8   | V    |
| Quiet output minimum dymnamic $V_{OL}$            | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0         | -0.4      | -0.8  | V    |
| Minimum high level dynamic input voltage $V_{IH}$ | VIHD             | $C_L = 50 \text{ pF}$  | 5.0         | _         | 3.5   | V    |
| Maximum low level dynamic input voltage $V_{IL}$  | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0         |           | 1.5   | V    |

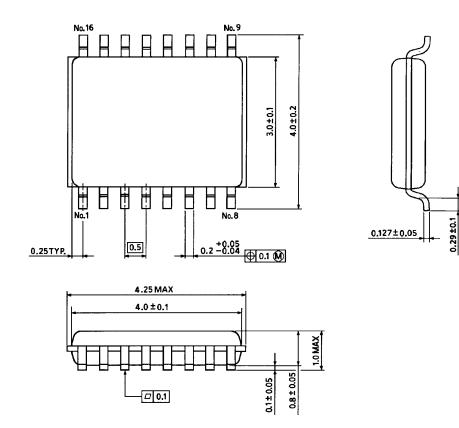
## Input Equivalent Circuit



#### **Package Dimensions**

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

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